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SNAS389C - JUNE 2007 - REVISED APRIL 2013

# LME49860 44V Dual High Performance, High Fidelity Audio Operational Amplifier

Check for Samples: LME49860, LME49860MABD, LME49860NABD

#### **FEATURES**

- Easily Drives 600Ω Loads
- **Optimized for Superior Audio Signal Fidelity**
- **Output Short Circuit Protection**
- PSRR and CMRR Exceed 120dB (Typ)
- **SOIC or PDIP Packages**

#### **APPLICATIONS**

- **Ultra High Quality Audio Amplification**
- **High Fidelity Preamplifiers**
- **High Fidelity Multimedia**
- State of the Art Phono Pre Amps
- **High Performance Professional Audio**
- **High Fidelity Equalization and Crossover Networks**
- **High Performance Line Drivers**
- **High Performance Line Receivers**
- **High Fidelity Active Filters**

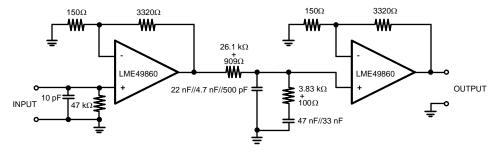
#### **KEY SPECIFICATIONS**

- Power Supply Voltage Range: ±2.5 to ±22V
- THD+N (A<sub>V</sub> = 1,  $V_{OUT} = 3V_{RMS}$ ,  $f_{IN} = 1kHz$ )
  - R<sub>L</sub> = 2kΩ: 0.00003% (Typ)
  - R<sub>L</sub> = 600Ω: 0.00003% (Typ)
- Input Noise Density: 2.7 nV/√Hz (Typ)
- Slew Rate: ±20V/µs (Typ)
- Gain Bandwidth Product: 55MHz (Typ)
- Open Loop Gain ( $R_L = 600\Omega$ ): 140dB (Typ)
- Input Bias Current: 10nA (Typ)
- Input Offset Voltage: 0.1mV (Typ)
- DC Gain Linearity Error: 0.000009%

#### DESCRIPTION

The LME49860 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49860 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49860 combines extremely low voltage noise density  $(2.7\text{nV}/\sqrt{\text{Hz}})$  with vanishingly low THD+N (0.00003%)to easily satisfy the most demanding audio applications.

#### TYPICAL APPLICATION



Note: 1% metal film resistors, 5% polypropylene capacitors

Figure 1. Passively Equalized RIAA Phono Preamplifier

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#### **DESCRIPTION (CONTINUED)**

To ensure that the most challenging loads are driven without compromise, the LME49860 has a high slew rate of  $\pm 20 \text{V/µs}$  and an output current capability of  $\pm 26 \text{mA}$ . Further, dynamic range is maximized by an output stage that drives  $2 \text{k} \Omega$  loads to within 1V of either power supply voltage and to within 1.4V when driving  $600 \Omega$  loads.

The LME49860's outstanding CMRR (120dB), PSRR (120dB), and  $V_{OS}$  (0.1mV) give the amplifier excellent operational amplifier DC performance.

The LME49860 has a wide supply range of ±2.5V to ±22V. Over this supply range the LME49860 maintains excellent common-mode rejection, power supply rejection, and low input bias current. The LME49860 is unity gain stable. This Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49860 is available in 8-lead narrow body SOIC and 8-lead PDIP packages. Demonstration boards are available for each package.

#### **Connection Diagrams**

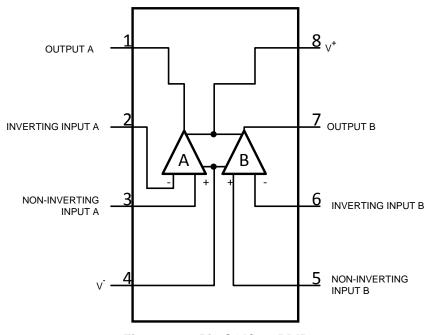


Figure 2. 8-Pin SOIC or PDIP See D or P Package



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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## ABSOLUTE MAXIMUM RATINGS(1)(2)(3)

Power Supply Voltage (V <sub>S</sub> = V <sup>+</sup> - V <sup>-</sup> )	Power Supply Voltage (V <sub>S</sub> = V <sup>+</sup> - V <sup>-</sup> )			
Storage Temperature		−65°C to 150°C		
Input Voltage	(V-) - 0.7V to (V+) + 0.7V			
Output Short Circuit <sup>(4)</sup>	Continuous			
ESD Susceptibility <sup>(5)</sup>	2000V			
ESD Susceptibility <sup>(6)</sup>	Pins 1, 4, 7 and 8	200V		
	Pins 2, 3, 5 and 6	100V		
Junction Temperature	•	150°C		
Thermal Resistance	θ <sub>JA</sub> (SOIC)	145°C/W		
	θ <sub>JA</sub> (PDIP)	102°C/W		

- 1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instrument Sales Office/ Distributors for availability and specifications.
- (4) Amplifier output connected to GND, any number of amplifiers within a package.
- (5) Human body model, 100pF discharged through a  $1.5k\Omega$  resistor.
- (6) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50Ω).

#### **OPERATING RATINGS**

Temperature Range	$T_{MIN} \le T_A \le T_{MAX}$	-40°C ≤ T <sub>A</sub> ≤ 85°C
Supply Voltage Range		$\pm 2.5 \text{V} \le \text{V}_{\text{S}} \le \pm 22 \text{V}$

### **ELECTRICAL CHARACTERISTICS FOR THE LME49860<sup>(1)</sup>**

The following specifications apply for  $V_S = \pm 18V$  and  $\pm 22V$ ,  $R_L = 2k\Omega$ ,  $R_{SOURCE} = 10\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^{\circ}C$ , unless otherwise specified.

0	D	did	LME4	9860	Units	
Symbol	Parameter	Con	ditions	Typical <sup>(2)</sup>	Limit <sup>(3)</sup>	(Limits)
THD+N	Total Harmonic Distortion + Noise	$A_V = 1$ , $V_{OUT} = 3V_{rms}$	$R_L = 2k\Omega$ $R_L = 600\Omega$	0.00003 0.00003	0.00009	% (max)
IMD	Intermodulation Distortion	$A_V = 1$ , $V_{OUT} = 3V_{RMS}$ , $T_W$	o-tone, 60Hz & 7kHz 4:1	0.00005		%
GBWP	Gain Bandwidth Product			55	45	MHz (min)
SR	Slew Rate			±20	±15	V/µs (min)
FPBW	Full Power Bandwidth	V <sub>OUT</sub> = 1V <sub>P-P</sub> , –3dB referenced to output magn	itude at f = 1kHz	10		MHz
t <sub>s</sub>	Settling time	$A_V = -1$ , 10V step, $C_L = 10$	00pF, 0.1% error range	1.2		μs
	Equivalent Input Noise Voltage	f <sub>BW</sub> = 20Hz to 20kHz		0.34	0.65	μV <sub>RMS</sub> (max)
e <sub>n</sub>	Equivalent Input Noise Density	f = 1kHz f = 10Hz		2.7 6.4	4.7	_nV <b>/</b> √H z (max)
in	Current Noise Density	f = 1kHz f = 10Hz		1.6 3.1		pA <b>/</b> √H z
.,	Office ( ) Valle and	V <sub>S</sub> = ±18V		±0.12	±0.7	mV (max)
V <sub>OS</sub>	Offset Voltage	V <sub>S</sub> = ±22V		±0.14	±0.7	mV (max)
ΔV <sub>OS</sub> /ΔTe mp	Average Input Offset Voltage Drift vs Temperature	-40°C ≤ T <sub>A</sub> ≤ 85°C		0.2		μV/°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Typical specifications are specified at +25°C and represent the most likely parametric norm.
- (3) Tested limits are ensured to AOQL (Average Outgoing Quality Level).



# ELECTRICAL CHARACTERISTICS FOR THE LME49860<sup>(1)</sup> (continued)

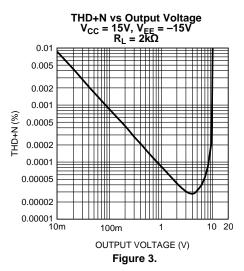
The following specifications apply for  $V_S = \pm 18V$  and  $\pm 22V$ ,  $R_L = 2k\Omega$ ,  $R_{SOURCE} = 10\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^{\circ}C$ , unless otherwise specified.

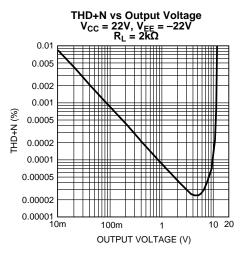
Symbol	Parameter	Conditions	LME4		Units
Symbol	Parameter		Typical <sup>(2)</sup>	Limit <sup>(3)</sup>	(Limits
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	See <sup>(4)</sup> $V_S = \pm 18V$ , $\Delta V_S = 24V$ $V_S = \pm 22V$ , $\Delta V_S = 30V$	120 120	110	dB dB (min)
ISO <sub>CH-CH</sub>	Channel-to-Channel Isolation	$f_{IN} = 1kHz$ $f_{IN} = 20kHz$	118 112		dB
l <sub>B</sub>	Input Bias Current	V <sub>CM</sub> = 0V	10	72	nA (max)
ΔI <sub>OS</sub> /ΔTe mp	Input Bias Current Drift vs Temperature	-40°C ≤ T <sub>A</sub> ≤ 85°C	0.1		nA/°C
los	Input Offset Current	V <sub>CM</sub> = 0V	11	65	nA (max)
.,	Common-Mode Input Voltage	V <sub>S</sub> = ±18V	+17.1 -16.9	(V+) - 2.0 (V-) + 2.0	V (min) V (min)
V <sub>IN-CM</sub>	Range	V <sub>S</sub> = ±22V	+21.0 -20.8	(V+) - 2.0 (V-) + 2.0	V (min) V (min)
01100		$V_S = \pm 18V$ -12V $\leq V_{CM} \leq 12V$	120		dB
CMRR	Common-Mode Rejection	$V_S = \pm 22V$ -15V \le V <sub>CM</sub> \le 15V	120	110	dB (min)
	Differential Input Impedance		30		kΩ
Z <sub>IN</sub>	Common Mode Input Impedance	-10V <vcm<10v< td=""><td>1000</td><td></td><td>ΜΩ</td></vcm<10v<>	1000		ΜΩ
Avol	Open Loop Voltage Gain	$\begin{aligned} &V_S = \pm 18V \\ &-12V \leq Vout \leq 12V \\ &R_L = 600\Omega \\ &R_L = 2k\Omega \\ &R_L = 10k\Omega \end{aligned}$	140 140 140		dB dB dB
		$V_S = \pm 22V$ $-15V \le Vout \le 15V$ $R_L = 600\Omega$ $R_L = 2k\Omega$ $R_L = 10k\Omega$	140 140 140	125	dB (min) dB dB
		$R_L = 600\Omega$ $V_S = \pm 18V$ $V_S = \pm 22V$	±16.7 ±20.4	±19.0	V V (min)
$V_{OUTMAX}$	Maximum Output Voltage Swing	$R_L = 2k\Omega$ $V_S = \pm 18V$ $V_S = \pm 22V$	±17.0 ±21.0		V
		$R_L = 10k\Omega$ $V_S = \pm 18V$ $V_S = \pm 22V$	±17.1 ±21.2		V
I <sub>OUT</sub>	Output Current	$R_L = 600\Omega$ $V_S = \pm 20V$ $V_S = \pm 22V$	±31 ±37	±30	mA mA (min)
I <sub>OUT-CC</sub>	Instantaneous Short Circuit Current		+53 -42		mA
R <sub>OUT</sub>	Output Impedance	f <sub>IN</sub> = 10kHz Closed-Loop Open-Loop	0.01 13		Ω
C <sub>LOAD</sub>	Capacitive Load Drive Overshoot	100pF	16		%
I <sub>S</sub>	Total Quiescent Current	$I_{OUT} = 0mA$ $V_S = \pm 18V$ $V_S = \pm 22V$	10.2 10.5	13	mA mA (max)

PSRR is measured as follows: For  $V_S = \pm 22V$ ,  $V_{OS}$  is measured at two supply voltages,  $\pm 7V$  and  $\pm 22V$ . PSRR =  $|\ 20log(\Delta V_{OS}/\Delta V_S)|$ .

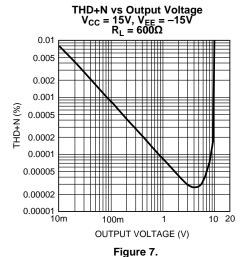


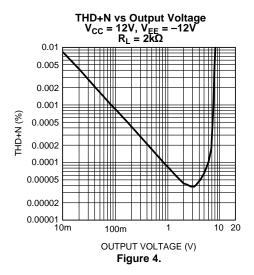
#### TYPICAL PERFORMANCE CHARACTERISTICS











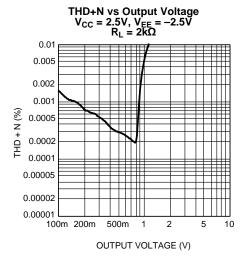


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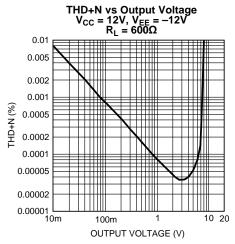


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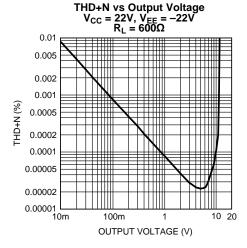
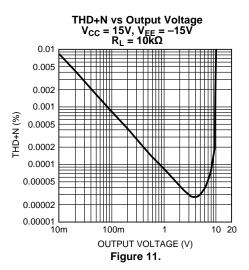


Figure 9.



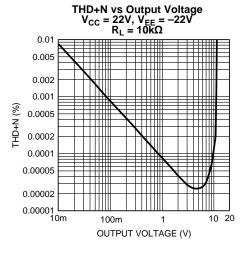


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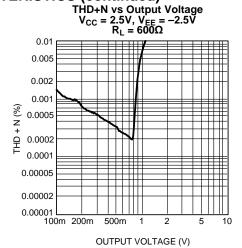
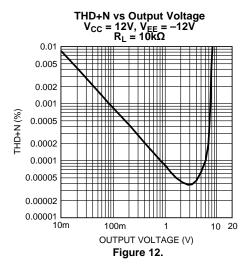


Figure 10.



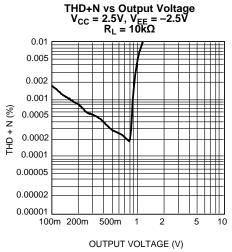


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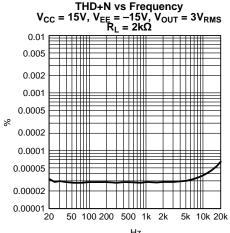


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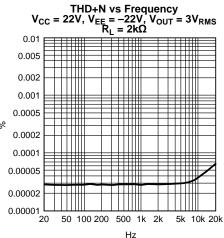
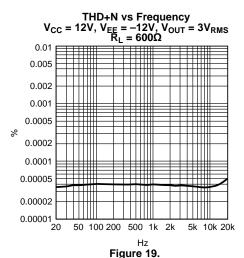
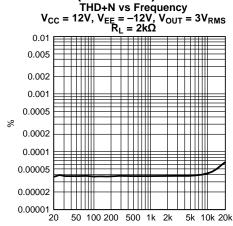


Figure 17.





Hz Figure 16.

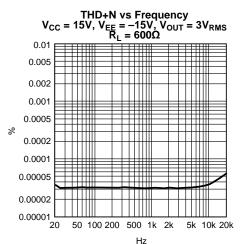


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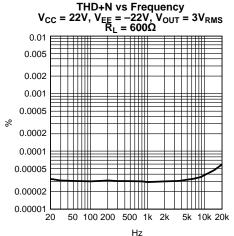


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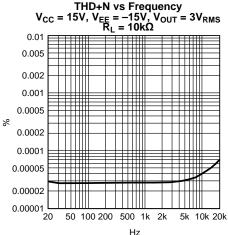


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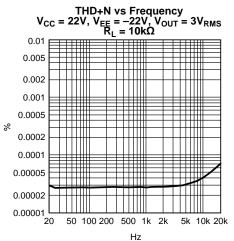
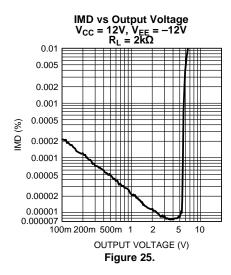


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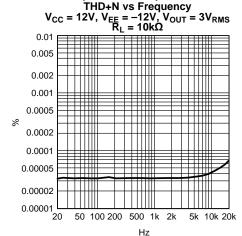
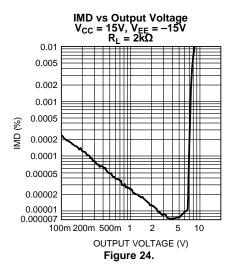


Figure 22.



 $| \text{MD vs Output Voltage} \\ V_{CC} = 22V, V_{EE} = -22V \\ R_L = 2k\Omega$   $| 0.001 \\ 0.0005 \\ | 0.0002 \\ 0.0001 \\ | 0.00005 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0.00002 \\ | 0$ 

(%) QW

0.00001

0.000007

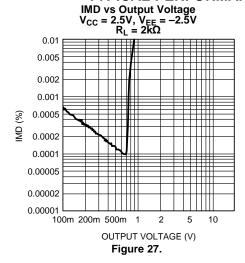
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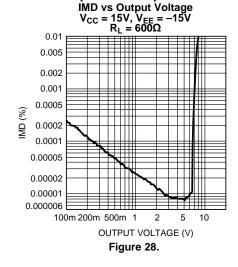
OUTPUT VOLTAGE (V)

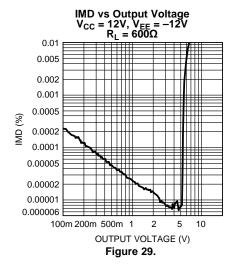
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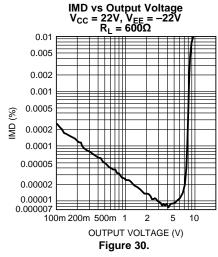
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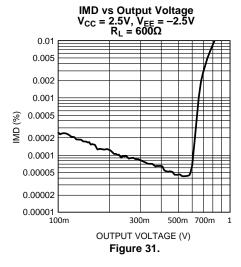


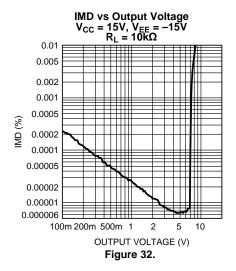




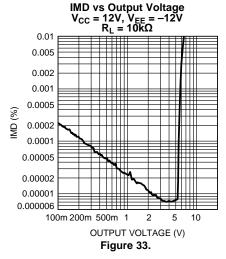


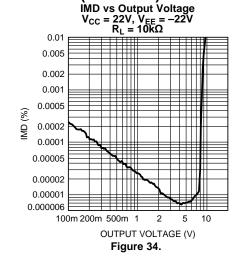


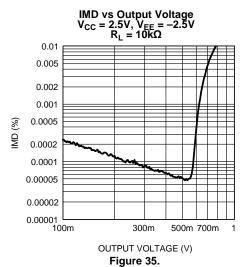


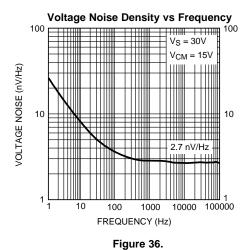


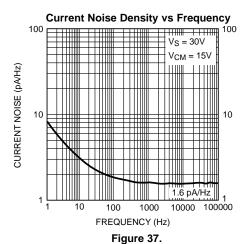


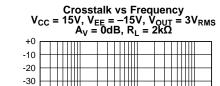












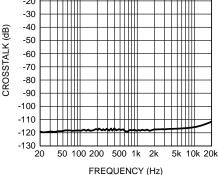
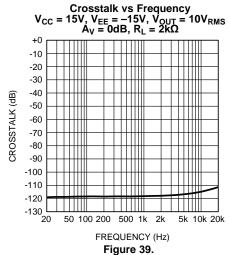
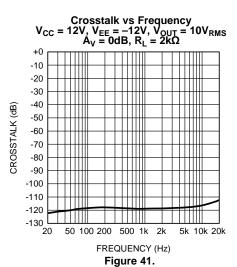
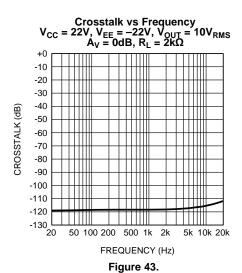


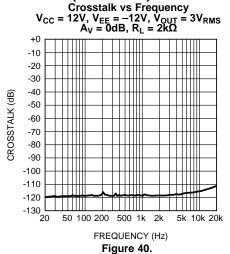
Figure 38.

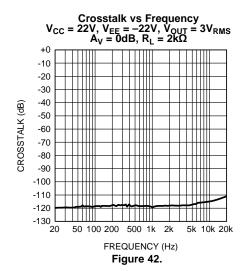












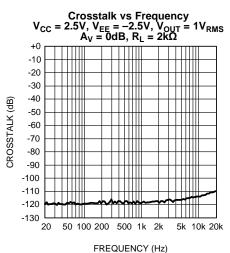
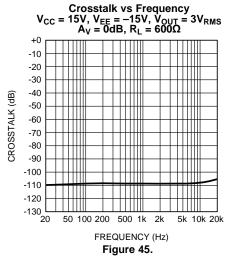
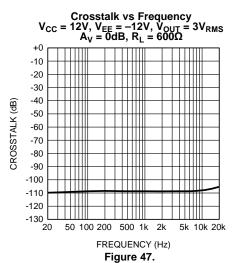
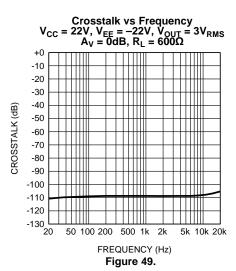


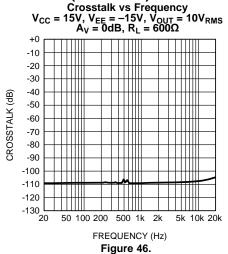
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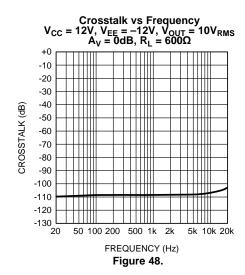


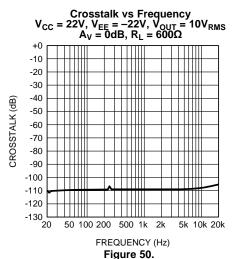














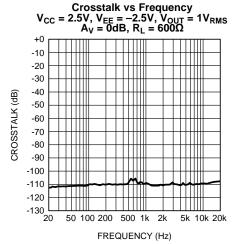


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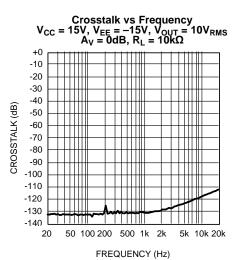


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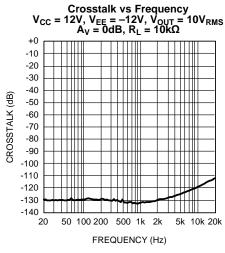


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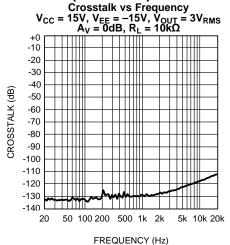


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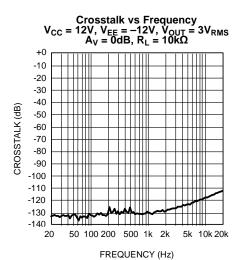


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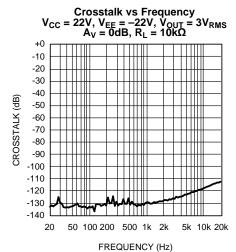


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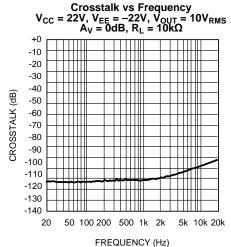
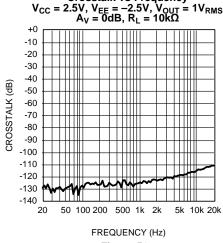


Figure 57.



Crosstalk vs Frequency

Figure 58.

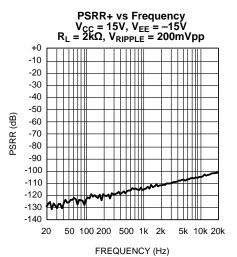


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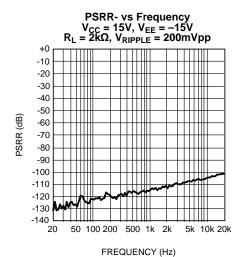
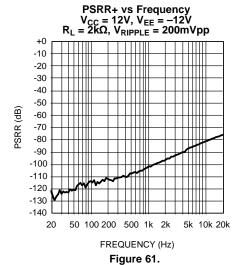


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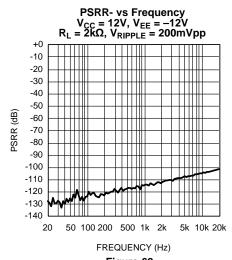


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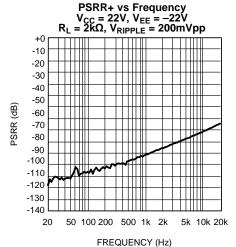


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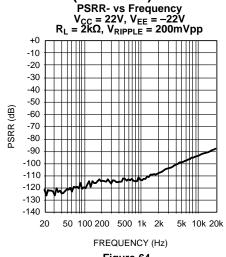


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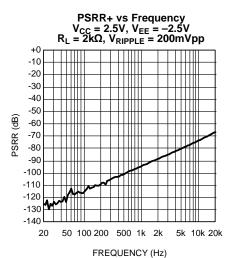


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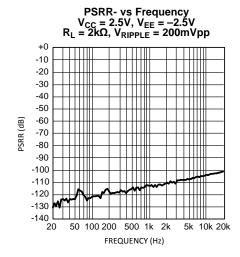
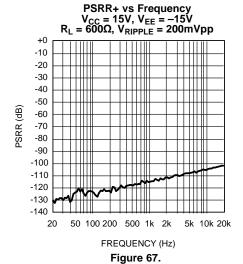


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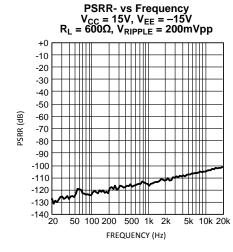


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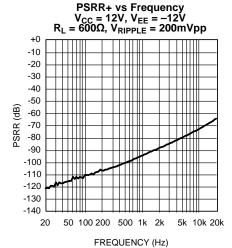
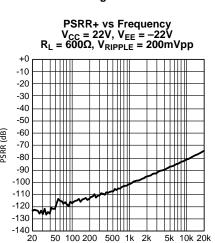
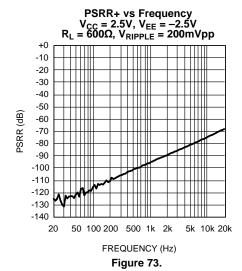


Figure 69.



FREQUENCY (Hz)

Figure 71.



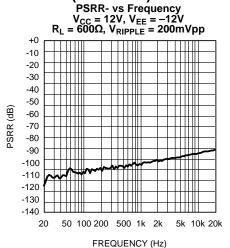


Figure 70.

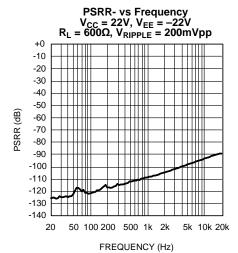


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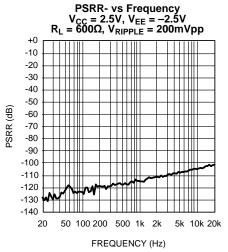


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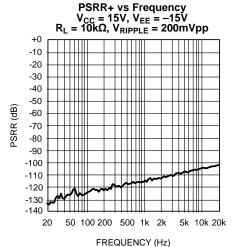


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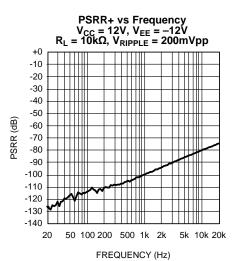
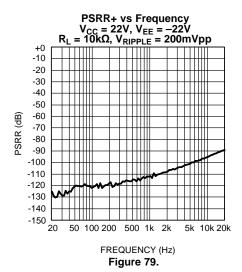


Figure 77.



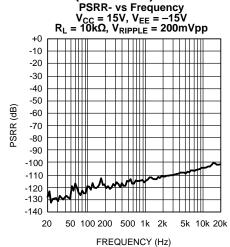


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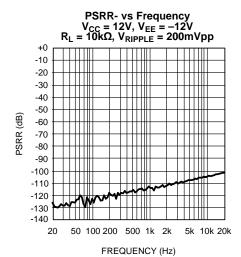


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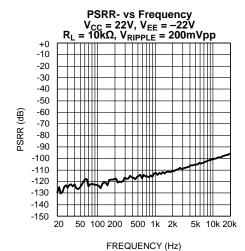
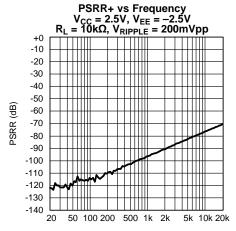
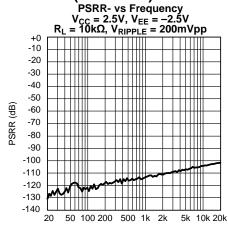


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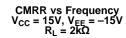




FREQUENCY (Hz) Figure 81.



FREQUENCY (Hz) Figure 82.



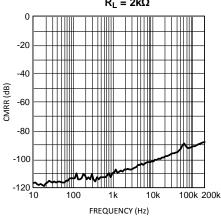


Figure 83.

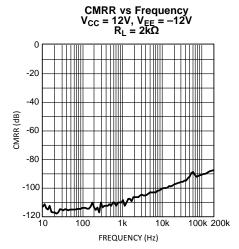
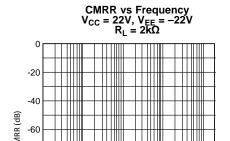


Figure 84.



FREQUENCY (Hz) Figure 85.

10k

100k 200k

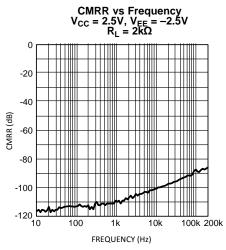


Figure 86.

100

-80

-100

-120 N



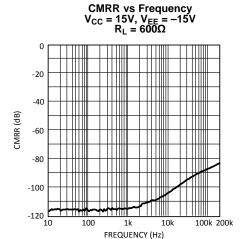
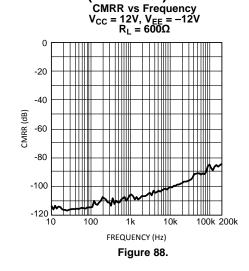


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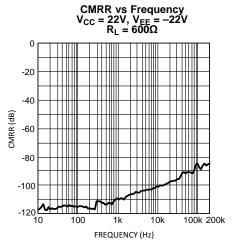


Figure 89.

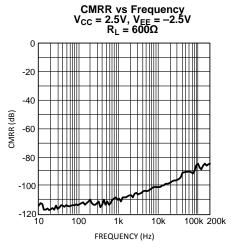


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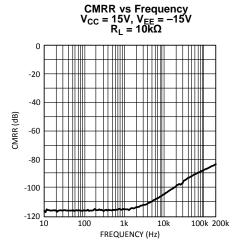


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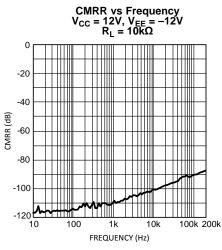


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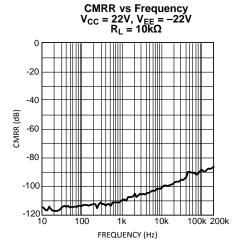


Figure 93.

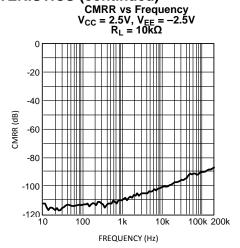
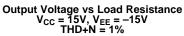
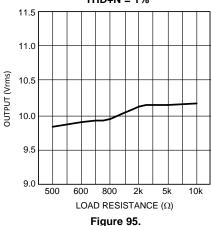
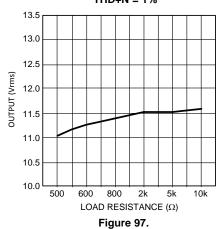


Figure 94.





Output Voltage vs Load Resistance  $V_{CC}$  = 22V,  $V_{EE}$  = -22V THD+N = 1%



Output Voltage vs Load Resistance  $V_{CC}$  = 12V,  $V_{EE}$  = -12V THD+N = 1%

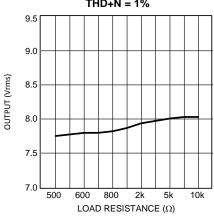


Figure 96.

# Output Voltage vs Load Resistance $V_{CC}$ = 2.5V, $V_{EE}$ = -2.5V THD+N = 1%

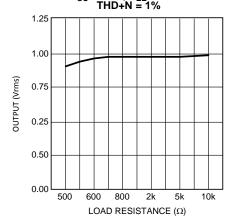


Figure 98.



#### **Output Voltage vs Total Power Supply Voltage** $R_L = 2k\Omega$ , THD+N = 1%

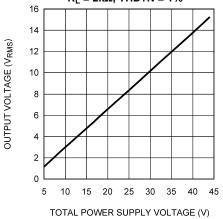
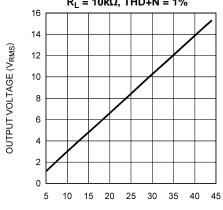


Figure 99.

# Output Voltage vs Total Power Supply Voltage $R_L = 10k\Omega, THD+N = 1\%$



TOTAL POWER SUPPLY VOLTAGE (V) Figure 101.

# Power Supply Current vs Total Power Supply Voltage $R_L$ = $600\Omega$

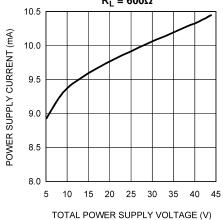


Figure 103.

# Output Voltage vs Total Power Supply Voltage $R_L = 600\Omega$ , THD+N = 1%

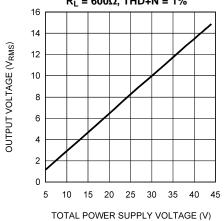
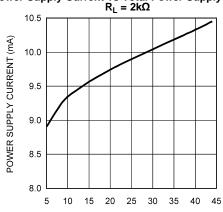


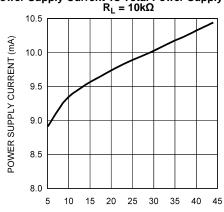
Figure 100.

### **Power Supply Current vs Total Power Supply Voltage**



TOTAL POWER SUPPLY VOLTAGE (V) Figure 102.

#### **Power Supply Current vs Total Power Supply Voltage**



TOTAL POWER SUPPLY VOLTAGE (V)

Figure 104.



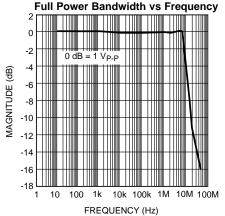


Figure 105.

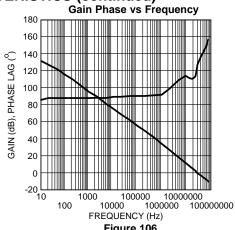


Figure 106.

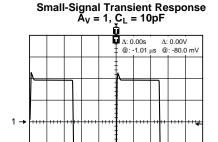
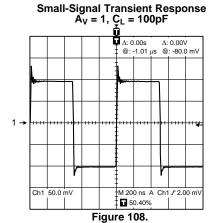


Figure 107.

50.40%

Ch1 50.0 mV

M 200 ns A Ch1 7 2.00 mV





#### **APPLICATION INFORMATION**

#### **DISTORTION MEASUREMENTS**

The vanishingly low residual distortion produced by LME49860 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49860's low residual distortion is an input referred internal error. As shown in Figure 109, adding the  $10\Omega$  resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 109.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.

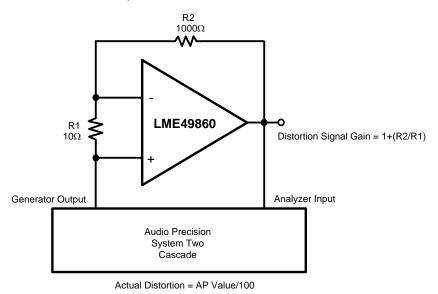
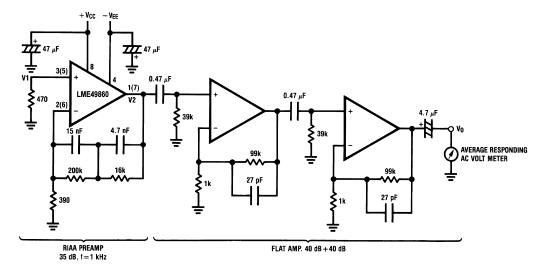


Figure 109. THD+N and IMD Distortion Test Circuit

The LME49860 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.





Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

Figure 110. Noise Measurement Circuit Total Gain: 115 dB @f = 1 kHz Input Referred Noise Voltage: e<sub>n</sub> = V0/560,000 (V)

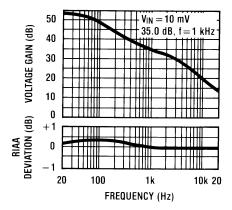


Figure 111. RIAA Preamp Voltage Gain, RIAA Deviation vs Frequency

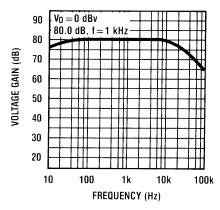
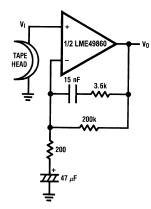


Figure 112. Flat Amp Voltage Gain vs Frequency



#### **TYPICAL APPLICATIONS**



 $A_V = 34.5$  F = 1 kHz  $E_n = 0.38 \text{ }\mu\text{V}$  A Weighted

Figure 113. NAB Preamp

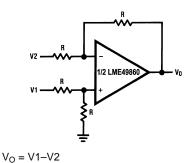


Figure 115. Balanced to Single Ended Converter

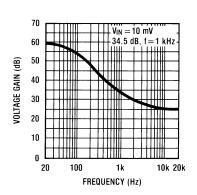


Figure 114. NAB Preamp Voltage Gain vs Frequency

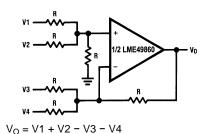
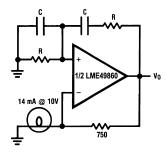


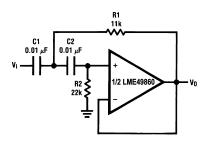
Figure 116. Adder/Subtracter



 $f_0 = \frac{1}{2\pi RC}$ 

Figure 117. Sine Wave Oscillator

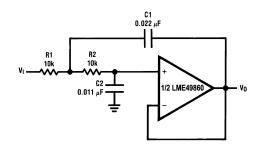




if C1 = C2 = C 
$$R1 = \frac{\sqrt{2}}{2\omega_0C}$$
 
$$R2 = 2 \cdot R1$$

Illustration is  $f_0 = 1 \text{ kHz}$ 

Figure 118. Second Order High Pass Filter (Butterworth)

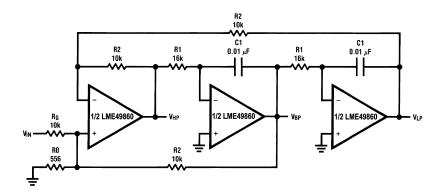


if R1 = R2 = R 
$$C1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C0 = \frac{C1}{\omega_0 R}$$

Illustration is  $f_0 = 1 \text{ kHz}$ 

Figure 119. Second Order Low Pass Filter (Butterworth)



$$f_0 = \frac{1}{2\pi C 1 R 1}, Q = \frac{1}{2} \left( 1 + \frac{R 2}{R 0} + \frac{R 2}{R G} \right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R 2}{R G}$$

Illustration is  $f_0 = 1 \text{ kHz}$ , Q = 10,  $A_{BP} = 1$ 

Figure 120. State Variable Filter

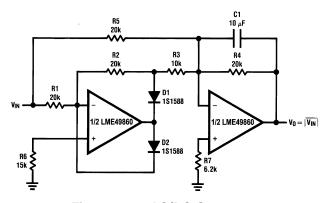
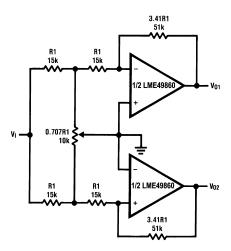


Figure 121. AC/DC Converter





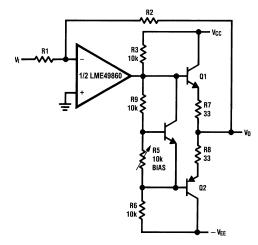
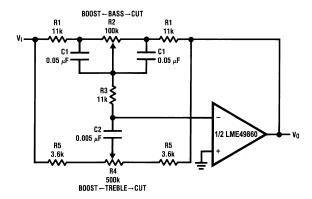


Figure 122. 2 Channel Panning Circuit (Pan Pot)

Figure 123. Line Driver



$$\begin{split} f_L &= \frac{1}{2\pi R2C1}, f_{LB} = \frac{1}{2\pi R1C1} \\ f_H &= \frac{1}{2\pi R5C2}, f_{HB} = \frac{1}{2\pi (R1 + R5 + 2R3)C2} \\ Illustration is: \\ f_L &= 32 \ Hz, \ f_{LB} = 320 \ Hz \\ f_H &= 11 \ kHz, \ f_{HB} = 1.1 \ kHz \end{split}$$

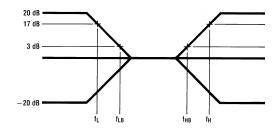
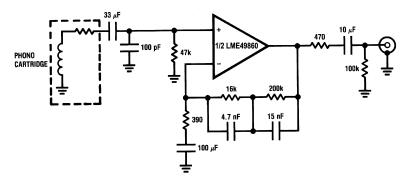


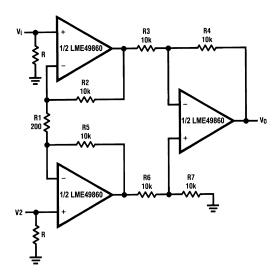
Figure 124. Tone Control





 $\begin{array}{l} A_v = 35 \text{ dB} \\ E_n = 0.33 \text{ } \mu\text{V} \\ \text{S/N} = 90 \text{ dB} \\ \text{f} = 1 \text{ kHz} \\ \text{A Weighted}, \text{ V}_{\text{IN}} = 10 \text{ mV} \\ \text{@f} = 1 \text{ kHz} \end{array}$ 

Figure 125. RIAA Preamp



If R2 = R5, R3 = R6, R4 = R7  $V0 = \left(1 + \frac{2R2}{R1}\right) \frac{R4}{R3} (V2 - V1)$ Illustration is: V0 = 101 (V2 - V1)

Figure 126. Balanced Input Mic Amp



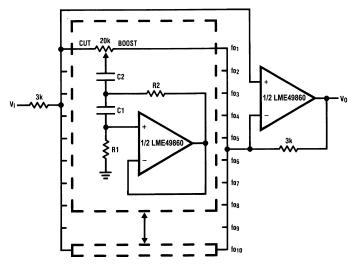


Figure 127. 10 Band Graphic Equalizer

fo (Hz)	C <sub>1</sub>	C <sub>2</sub>	R <sub>1</sub>	R <sub>2</sub>
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015µF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω



#### **REVISION HISTORY**

Rev	Date	Description
1.0	06/01/07	Initial release.
1.1	06/11/07	Added the LME49860MA and LME49860NA Top Mark Information.
С	04/05/13	Changed layout of National Data Sheet to TI format.



#### PACKAGE OPTION ADDENDUM

6-Feb-2020

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LME49860MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 85	L49860 MA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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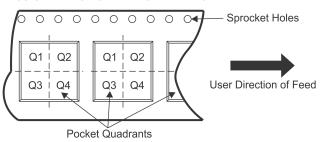
#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49860MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49860MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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